

#### Faculty of Engineering & Technology

#### **Semiconductor Devices**

#### Information:

Course Code: ELE 522 Level: Undergraduate Course Hours: 3.00- Hours

**Department:** Specialization of Electronics & Communication

### Area Of Study:

Ántroduce advanced semiconductor devices

ADevelop a detailed understanding of the design, operating mechanisms and fabrication technology of semiconductor electronic and optoelectronic devices.

Ántroducing the design parameters, performance parameters, CAD models, device scaling theory, etc.

#### **Description:**

Metal-Semiconductor junctions (Schottky barriers), Heterojunctions, Solar cells, Light emitting diodes, Photodetector diodes, JFET's, MESFET's, MOSFET's, VLSI bipolar and MOS devices, CCD's power devices (PIN and rectifier diodes, SCR's, power switching transistors).

Course ou	tcomes:		
a.Knowled	ge and Understanding: :		
1 -	Describe the basic operation of advanced semiconductor devices and their characteristics.		
2 -	Define design features that determine the device characteristics.		
3 -	Define the device models for circuit simulation.		
b.Intellectu	ual Skills: :		
1 -	Develop analytical models for the advanced semiconductor devices		
2 -	Use compact device models for circuit simulation		
3 -	Use semiconductor devices for material and process characterization.		
4 -	Examine a detailed understanding of the many and diverse aspects that relate to the operation and exploitation of semiconductor devices.		
c.Profession	onal and Practical Skills: :		
1 -	Develop a practical circuit simulation using compact device models		
2 -	Develop technical report writing skills		
3 -	Design, model and analyze a number of semiconductor device types.		
d.General	and Transferable Skills: :		
1 -	Communicate effectively.		
2 -	Demonstrate Efficient IT capabilities using modern software tools		



Course Topic And Contents :			
Topic	No. of hours	Lecture	Tutorial / Practical
Metal-Semiconductor junctions	5	3	2
Heterojunctions, Solar cells	5	3	2
Solar cells	5	3	2
Light emitting diodes	5	3	2
Photodetector diodes	5	3	2
JFET's and MESFET's	10	6	4
MOSFET's	10	6	4
VLSI bipolar and MOS devices	10	6	4
CCD's power devices (PIN and rectifier diodes).	10	6	4
SCR's, power switching transistors	10	6	4

# **Teaching And Learning Methodologies:**

Interactive Lecturing

**Problem Solving** 

Discussion

**Experiential Learning** 

**Project** 

Course Assessment :						
Methods of assessment	Relative weight %	Week No	Assess What			
Quizzes	10.00					
Assignments	5.00					
Final Exam	40.00					
Lab and Project	15.00					
Mid Term I	15.00					
Mid Term II	15.00					

#### **Course Notes:**

Taken by the student inside classroom

## **Recommended books:**

- R.F. Pierret. Semiconductor Fundamentals ÉPearson, 2nd Ed., 1998. Chenming Hu, Modern Semiconductor Devices for Integrated Circuits ÉPearson, First edition, 2009.

#### Periodicals:

- IEEE periodicals, Nanohub.org

